NSN 5961-01-228-8306

Transistor - Page 1 of 2



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Inclosure Material:
Metal
Overall Length:
0.260 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.335 inches
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-5
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
3.00 amperes source cutoff current
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector preset
Transfer Ratio:
150.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:

NI/o

Shelf Life:

81349-mil-s-19500/349 government specification

NSN 5961-01-228-8306

Transistor - Page 2 of 2



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Demilitarization:

No

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